

665nm 8mW VCSEL Laser Chip

Part No.: D-V0665M-0008-0007

Suitable for pulse power applications and the power is 8mW



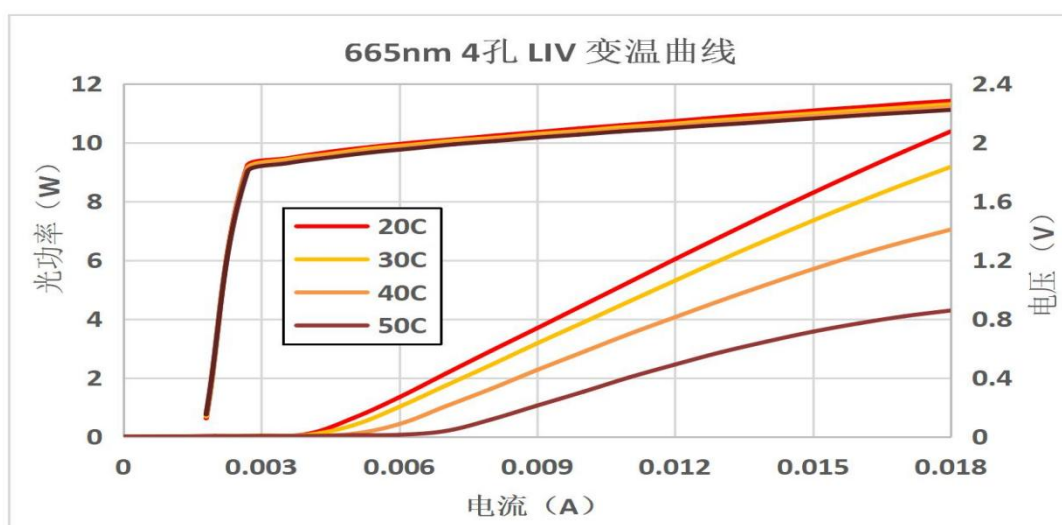
Features

- VCSEL (Vertical-Cavity Surface-Emitting Laser)
- High efficiency and reliability
- Stable central wavelength, narrow line width
- Doughnut shaped, symmetrical far field
- Surface mountable

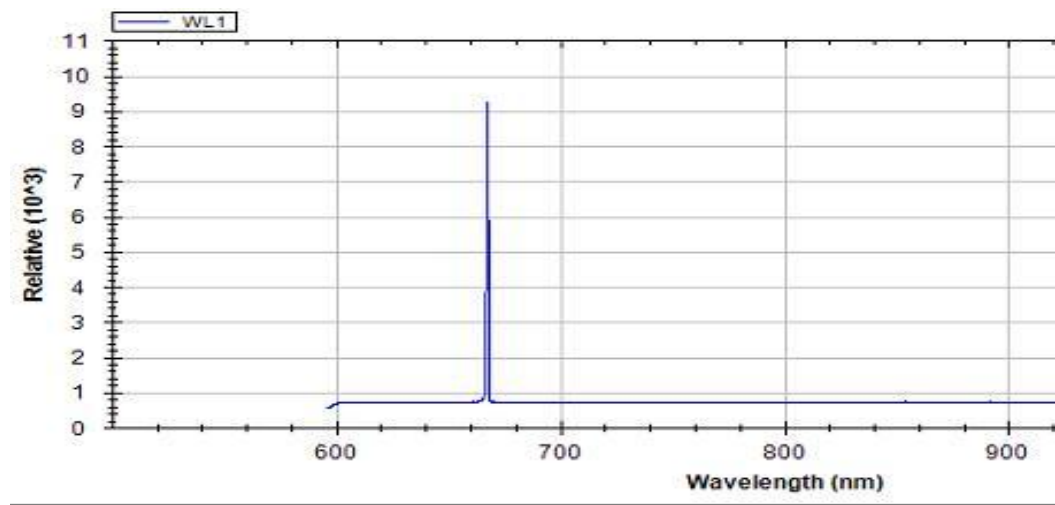
Applications

- Sensor light source
- Consumer electronic products
- Machine vision
- Red lighting

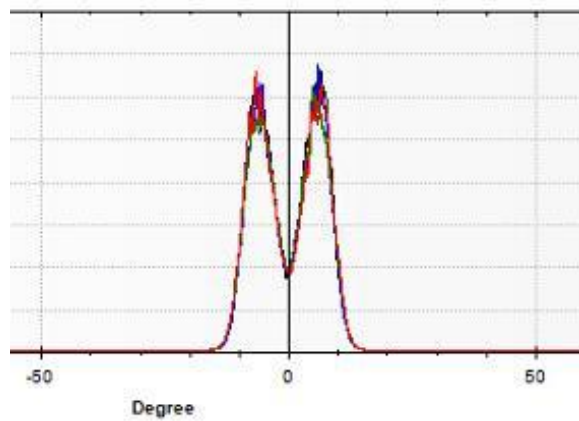
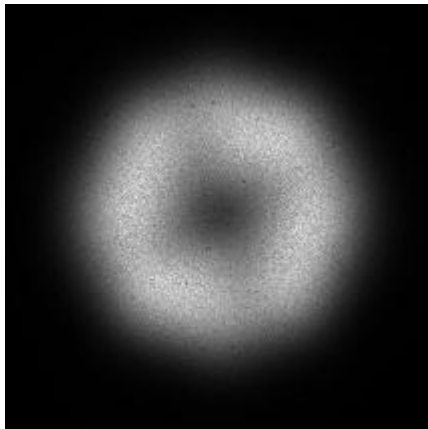
L-I-V



Spectroscopy



FFDA (Far-Field Divergence Angle) ($\sim 22^\circ$ at 15 mA)



Electrical Optical Characteristics

Parameter	Symbol	Unit	Min.	Typ.	Max	Note
Threshold Current	I _{th}	mA	3.5	4.5		
Forward Voltage	V _F	V	2.2	2.4		IF = 15mA
Output Power	P _{op}	mW	6.0	8.0		IF = 15mA
Slop Efficiency	SE	W/A	0.55	0.7		
Power Conversion Efficiency	PCE	%	17	22		IF = 15mA
Wavelength	λ _{op}	nm	660	665	670	
Divergence Angle(1/e ²)		deg		22		IF = 15mA

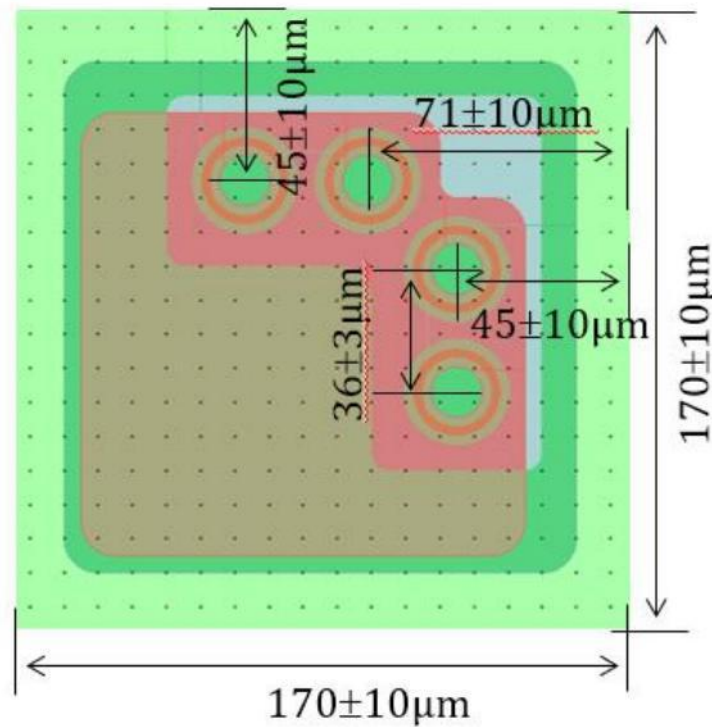
25°C, QCW Model (Pulse length 0.5ms, 1% Duty Cycle)

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The details in this document may subject to change without prior notice.

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Mechanical Specifications



参数 Parameter	规格 Specification
芯片尺寸 Die size	$170 \pm 10 \mu\text{m} \times 170 \pm 10 \mu\text{m}$
芯片厚度 Die Thickness	$130 \pm 10 \mu\text{m}$
光孔数目 Number of Emitters	4
焊盘尺寸 (正极) Bond Pad Size (Anode Pad)	$87 \pm 3 \mu\text{m} \times 85 \pm 3 \mu\text{m}$
背面电极尺寸 (负极) Back Electrode Size (Cathode Pad)	$170 \pm 10 \mu\text{m} * 170 \pm 10 \mu\text{m}$

